

8-input NAND gate**74HC/HCT30****FEATURES**

- Output capability: standard
- I_{CC} category: SSI

GENERAL DESCRIPTION

The 74HC/HCT30 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT30 provide the 8-input NAND function.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t _{PHL} / t _{PLH}	propagation delay A, B, C, D, E, F, G, H to Y	C _L = 15 pF; V _{CC} = 5 V	12	12	ns
C _I	input capacitance		3.5	3.5	pF
C _{PD}	power dissipation capacitance per gate	notes 1 and 2	15	15	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in µW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$$
 where:
 - f_i = input frequency in MHz
 - f_o = output frequency in MHz
 - $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs
 - C_L = output load capacitance in pF
 - V_{CC} = supply voltage in V
2. For HC the condition is V_I = GND to V_{CC}
For HCT the condition is V_I = GND to V_{CC} - 1.5 V

ORDERING INFORMATION

See "[74HC/HCT/HCU/HCMOS Logic Package Information](#)".

8-input NAND gate

74HC/HCT30

DC CHARACTERISTICS FOR 74 HC

For the DC characteristics see "[74HC/HCT/HCU/HCMOS Logic Family Specifications](#)".

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AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T_{amb} ($^{\circ}$ C)							UNIT	TEST CONDITIONS				
		74HC								V_{CC} (V)	WAVEFORMS			
		+25			−40 to +85		−40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
t_{PHL}/t_{PLH}	propagation delay A, B, C, D, E, F, G, H to Y	41 15 12	130 26 22		165 33 28		195 39 33	ns	2.0 4.5 6.0	Fig.6				
t_{THL}/t_{TLH}	output transition time	19 7 6	75 15 13		95 19 16		110 22 19	ns	2.0 4.5 6.0	Fig.6				

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see "[74HC/HCT/HCU/HCMOS Logic Family Specifications](#)".

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Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications.To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
A, B, C, D, E, F, G, H	0.60

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T_{amb} ($^{\circ}$ C)							UNIT	TEST CONDITIONS				
		74HCT								V_{CC} (V)	WAVEFORMS			
		+25			−40 to +85		−40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
t_{PHL}/t_{PLH}	propagation delay A, B, C, D, E, F, G, H to Y	16	28		35		42	ns	4.5	Fig.6				
t_{THL}/t_{TLH}	output transition time	7	15		19		22	ns	4.5	Fig.6				